| SiC10A065T-AU | |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|
| SILICON CARBIDE SCHOTTKY DIODE | |
| Voltage 650 V Current 10 A | TO-220AC |
| Features • Temperature Independent Switching Behavior • Low Conduction and Switching Loss • High Surge Current Capability • Positive Temperature Coefficient on V _F • Fast Reverse Recovery • Acquire quality system certificate : TS16949 • AEC-Q101 qualified Mechanical Data • Case: Molded plastic, TO-220AC • Marking: 10A065T | 0.419(10.66) 0.387(9.85) 20.156(3.95) 20.147(3.75) 0.008(0.96) 0.038(0.96) 0.019(0.50) 0.019(0.50) |
| Benefits High Frequency Operation Higher System Efficiency Environmental Protection Parallel Device Convenience Hard Switching & High Reliability High Temperature Application | 0.019(0.50) ① ③ ③ ↓ 0.100(2.54) ↓ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ ○ |

Maximum Ratings

PAN

_

SEMI CONDUCTOR

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUE | UNITS |
|-----------------------------------------------|------------------|-----------------|-------|-------|
| Maximum Repetitive Peak Reverse Voltage | Vrrm | TJ=25°C | 650 | V |
| Maximum RMS Voltage | Vrsm | TJ=25°C | 650 | V |
| Maximum DC Blocking Voltage | Vr | TJ=25°C | 650 | V |
| | | Tc=25°C | 25 | А |
| Continuous Forward Current | IF(AV) | Tc=125°C | 14 | А |
| | | Tc=150°C | 10 | А |
| Repetitive Peak Forward Surge Current | | Tc=25°C | 59 | А |
| (T _P =10mS, Half Sine Wave, D=0.1) | I _{FRM} | Tc=125°C | 50 | А |

Unit: inch(mm)

0.196(5.00) 0.163(4.16)

0.054(1.39) 0.045(1.15)

0.146(3.7) 0.130(3.3)

0.115(2.92) 0.080(2.03)

0.025(0.65)MAX.



SiC10A065T-AU

Maximum Ratings

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUE | UNITS |
|-------------------------------------------|-----------------------|-----------------|------------|-------|
| Non-Repetitive Peak Forward Surge Current | | Tc=25°C | 69 | А |
| (T _P =10mS, Half Sine Wave) | | Tc=125°C | 63 | А |
| Non-Repetitive Peak Forward Surge Current | I _{FSM} | Tc=25°C | 400 | A |
| (T _P =10uS, Pulse) | | | | |
| Deven Dissipation | P _D | Tc=25°C | 115 | W |
| Power Dissipation | | Tc=125°C | 38 | W |
| Operating Junction Temperature | TJ | | 175 | °C |
| Storage Temperature | T _{STG} | | -55 to 175 | °C |
| Thermal Resistance Junction to Case | $R_{	extsf{	heta}JC}$ | | 1.3 | °C/W |

Electrical Characteristics

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|-------------------------|-----------------|--------------------------------------------------|------|------|------|-------|
| DC Blacking Voltage | V _{DC} | I _R =100uA, TJ=25 [°] C | 650 | 770 | - | V |
| Forward Voltage | V _F | I _F =10A, TJ=25°C | - | 1.5 | 1.8 | V |
| | | I _F =10A, TJ=175°C | - | 1.9 | 2.2 | V |
| Reverse Current | I _R | V _R =650V, TJ=25°C | - | 5 | 70 | uA |
| | | V _R =650V, TJ=175°C | - | 20 | 190 | uA |
| Total Capacitive Charge | Qc | I _F =10A, di/dt=300A/uS, | - | 18 | - | nC |
| | | V _R =400V, TJ=25°C | | | | |
| Total Capacitance | С | V _R =1V, T _J =25°C, f=1MHz | - | 390 | - | pF |
| | | V _R =200V, TJ=25°C, f=1MHz | - | 55 | - | pF |
| | | V _R =400V, TJ=25°C, f=1MHz | - | 54 | - | pF |

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20 100 Reverse Leakage Current (uA) 18 16 Forward Current (A) 80 14 12 60 10 8 Tj=25°C 40 Tj=75°C 6 Tj=25°C Tj=125°C Tj=75°C 4 20 Tj=175°C Tj=125°C 2 Tj=175°C 0 0 1.0 1.5 2.0 2.5 Forward Voltage (V) 200 400 600 Reverse Voltage (V) 0.0 0.5 3.0 3.5 0 800 **Fig.1 Forward Characteristics Fig.2 Reverse Characteristics** 400 10³ Tc=25°C Non-Repetitive Forward 300 Capacitance (pF) Surge Current (A) 200 10² 100 0 10¹ 10² 10³ Pulse Width (uS) 10¹ 0 10 100 1000 10⁴ **Reverse Voltage (V)** Fig.4 Non-Repetitive Peak Forward Surge Current Fig.3 Capacitance vs. Reverse Voltage (Pulse Mode) 120 30 Peak Forward Current (A) 25 Power Dissipation (W) 100 V_{DC} 80 20 15 60 40 10 20 5 0 ∟____ 25 0 75 100 125 1 Case Temperature (°C) 50 75 100 125 150 175 25 50 175 150 Case Temperature (°C) **Fig.5 Power Derating Fig.6 Current Derating**



SiC10A065T-AU

TYPICAL CHARACTERISTIC CURVES



SiC10A065T-AU

Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|------------------------|--------------|--------------|---------|--------------|
| SIC10A065T-AU_T0_000A1 | TO-220AC | 50pcs / Tube | 10A065T | Halogen free |



SiC10A065T-AU

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